

Updates on charge sharing and radiation hardness of AC-LGADs for near-future Higgs factories and nuclear physics experiments

C. Bishop, A. Borjigin, A. Das, J. Ding, M. Gignac, S.M. Mazza, A. Molnar, M. Nizam, Jennifer Ott, T. Shin, G. Stage, Y. Zhao, H.F.-W. Sadrozinski, A. Seiden, B. Schumm

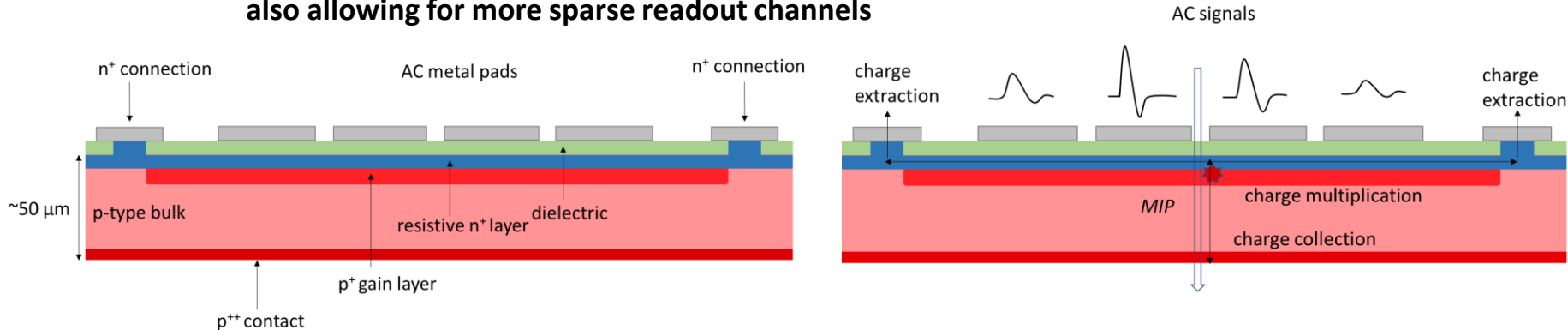
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CPAD Workshop

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AC-coupled LGADs

- Low to moderate gain (5-50) provided by p^+ multiplication layer
- Thin active volume to reduce charge drift time and Landau fluctuations of energy deposition, typical thickness 50 μm or less – provided on top of low-resistivity support wafer of 200-500 μm
- ‘Resistive Silicon Detectors’ (RSD): more resistive front side n^+ implant than in standard Si sensors
- Continuous dielectric, n^+ implant, and gain layer; patterned metal readout electrodes
 - No junction termination extension or p-stop between electrodes: fill factor ~ 100
 - Mirroring of charge at the n^+ layer on the metal pads: AC-coupling
 - Strong sharing of charge between metal pads
 - **Extrapolation of position based on signal sharing – finer position resolution for larger pitch, also allowing for more sparse readout channels**





AC-LGADs in future detectors

Electron-Ion Collider

- ePIC detector Barrel-TOF, forward-TOF, far-forward/Roman pots
 - AC-LGADs for time-of-flight particle ID: t_0 determination and timing, and serving as additional layer in Tracking
 - Combination of precise temporal and spatial resolution: 25-35 ps and 30 μm
 - Active thickness
 - Strip and pad electrode geometry
 - Resistivity of n+ layer and capacitance of coupling dielectric
 - **Radiation hardness**
 - **Angular hit performance**
- } *Extensive studies done, presented e.g. earlier in this session*

PIONEER

- LGADs (AC- or trench-insulated LGADS) for 4D/5D tracking
 - Thicker sensors to reduce ratio of dead material or gaps
 - More relaxed timing resolution requirements (100-200 ps)
 - **Angular hit performance**

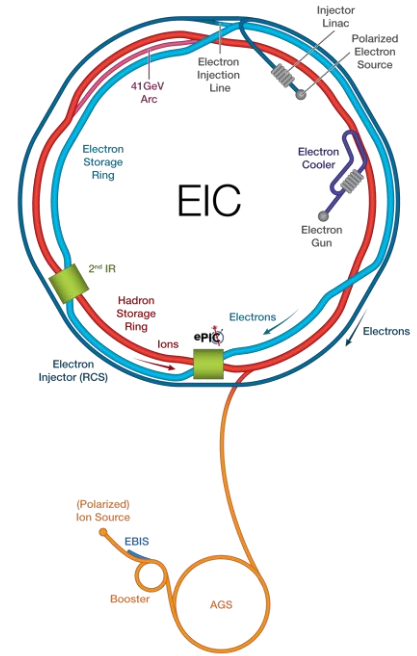
FCC-ee detector designs: IDEA 'silicon wrapper'

- True 4D tracking in all layers may not be needed in ee phase, but strip AC-LGAD layer would provide a time stamp and good spatial resolution at a comparatively sparse readout channel count

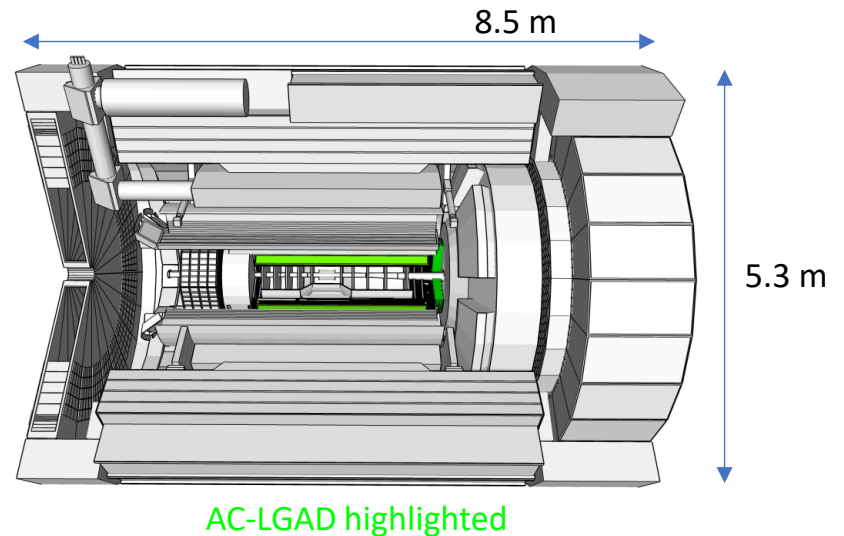
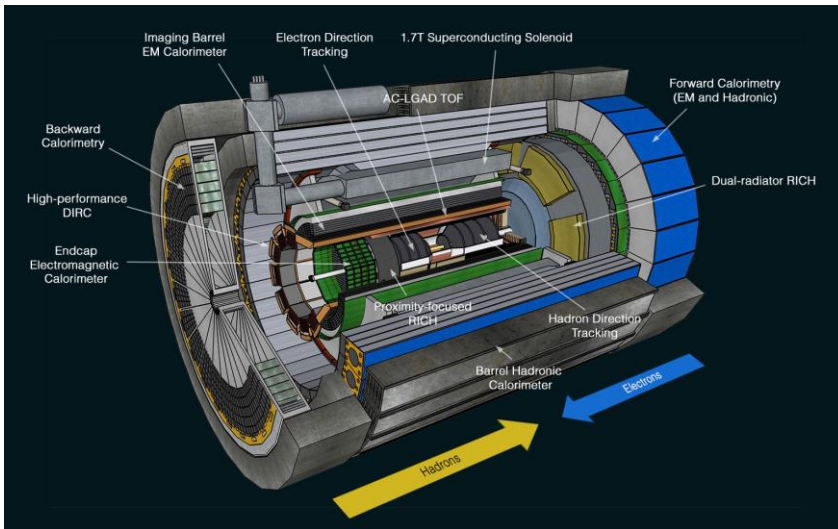
ePIC detector at the Electron-Ion Collider



- EIC Detector 1 → **ePIC Collaboration**
- Operations scheduled to begin 2032-2034
- Center-of-mass energy: **20 –140 GeV**
 - electrons: 2.5 –18 GeV
 - protons: 40 –275 GeV (ions: $Z/A * E_p$)
- **Luminosity: $2 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$**
- **Design includes AC-LGADs for time-of-flight particle ID, t_0 determination, and serving as additional layer in Tracking**



J. Ott et al, AC-LGADs, CPAD

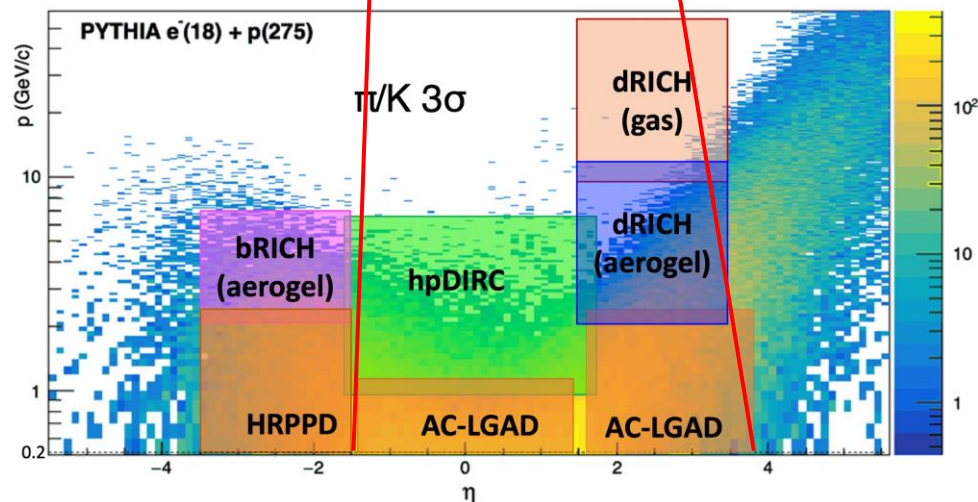
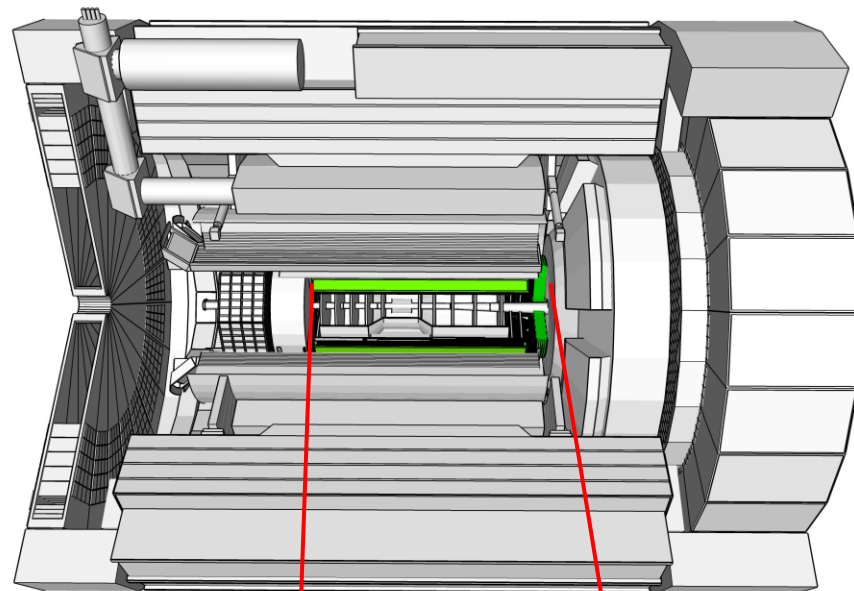


<https://indico.bnl.gov/event/17072/contributions/68825/>
<https://indico.bnl.gov/event/17072/contributions/70500/>

Particle-ID in ePIC



- Several detectors for particle ID in inner or outer barrel layers, hadronic endcap, electron endcap
 - Momentum and rapidity range cannot be covered by a single technology
 - Leveraging variants of Cherenkov detectors
 - AC-LGADs replaced by picosecond photodetectors in electron (backward) endcap
 - Excellent performance in distinction of charged particle species at low momenta < 3 GeV
- AC-LGAD barrel and forward-endcap Time-of-Flight PID
 - **Combination of precise temporal and spatial resolution: 25 ps and 30 μm / hit**
 - Low material budget
- Current sensor design baseline:
 - Barrel: **strips, 500 μm pitch and 1 cm length**
 - Hadronic endcap (and Roman Pots): **pads, 500 x 500 μm**

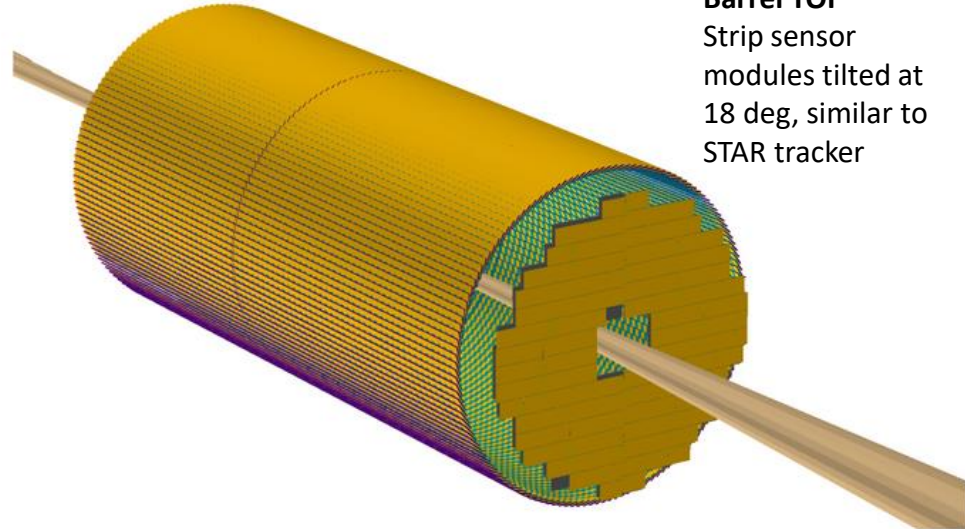


Particle ID systems in ePIC

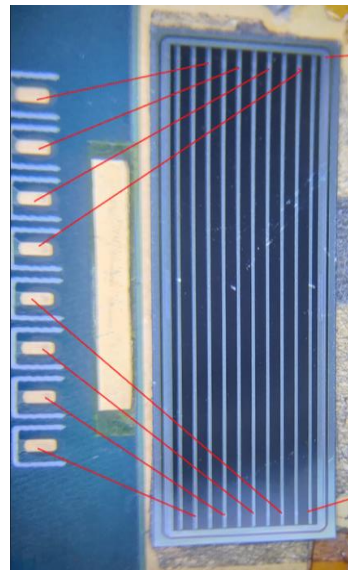
Particle-ID in ePIC



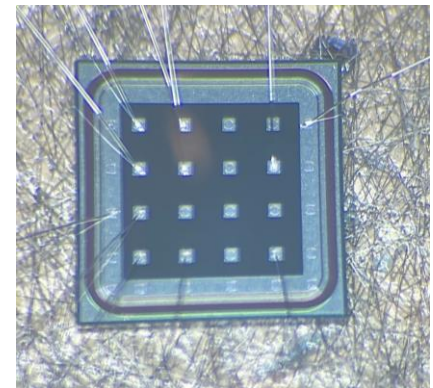
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Barrel TOF
Strip sensor modules tilted at 18 deg, similar to STAR tracker



Forward TOF
Similar to CMS ETL

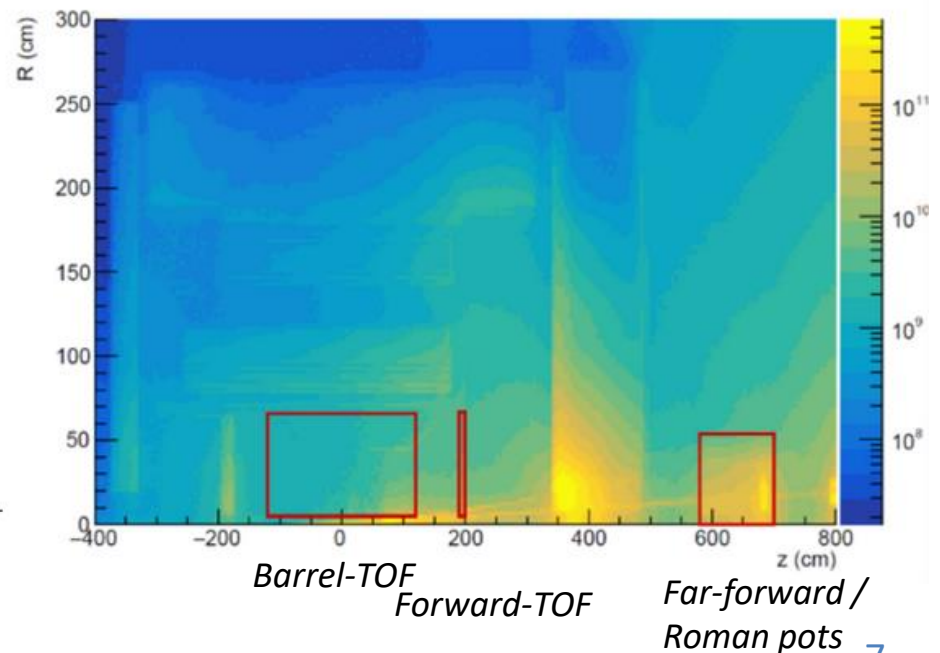


Radiation levels at ePIC

- **Radiation hardness of LGADs has been studied and optimized extensively for the HL-LHC timing endcap upgrades in ATLAS and CMS**
 - Focus on acceptor removal, gain layer doping deactivation
 - Relatively large-pad, conventional (DC-coupled) LGADs
- **At the EIC: radiation levels will be much lower than at the LHC: under certain assumptions, sensors should receive $< 5e12 \text{ cm}^{-2}$ over their lifetime**
 - **ePIC will feature AC-LGADs with resistive n^+ layer, which may be susceptible to radiation damage by changes in the n^+ electrode and the coupling dielectric**

RAW fluence			
System	Average	Min	Max
Barrel	5.4×10^{10}	3.4×10^{10}	5.9×10^{11}
End-cap	1.3×10^{11}	5.1×10^{10}	1.6×10^{12}
B0 trackers	3.9×10^{11}	3.3×10^{10}	1.8×10^{12}
NEQ fluence			
System	Average	Min	Max
Barrel	3.6×10^{10}	1.1×10^{10}	1.3×10^{12}
End-cap	1.2×10^{11}	3.2×10^{10}	8.4×10^{11}
B0 trackers	4.5×10^{11}	2.7×10^{10}	4.2×10^{12}

Table 8.2: RAW and NEQ fluence per system for the lifetime of the ePIC experiment, assuming 10 years of data taking at 50% time.



Irradiation campaign for AC-LGADs

- Subset of HPK (and BNL) sensors was irradiated with reactor neutrons at JSI/Ljubljana
 - Focus on E type and 50 μm thickness for strips – include 0.5, 1, 2 cm lengths
 - Focus on 150 μm pad size – include more wafers
- Total fluences between $1\text{e}12$ and $1\text{e}15$ n/cm^2 – some much higher than envisioned at the EIC over the full time of life, but better to have more margin, also taking into account the different doses especially in the forward high- η region
- Strip width 50 μm ; pixels primarily 150 μm , some 300 μm

Fluence	V(GL)	W2	W4	W5	W8	W9	W11
Thickness	50 μm	50 μm	50 μm	50 μm	20 μm	20 μm	
Capacitance		240	240	600	600	600	600
N+ resistivity		2	0.5	2	0.5	2	0.5
1.00E+12		54.5	52	54.5	52	53	
1.00E+13		54.5	51.5	54	51.5	53	
1.00E+14		51	50	51.5	49	50	
5.00E+14		41		42.5		41	38.5
1.00E+15		32				34	31

Pixels

Strips
W2

Strips
W5

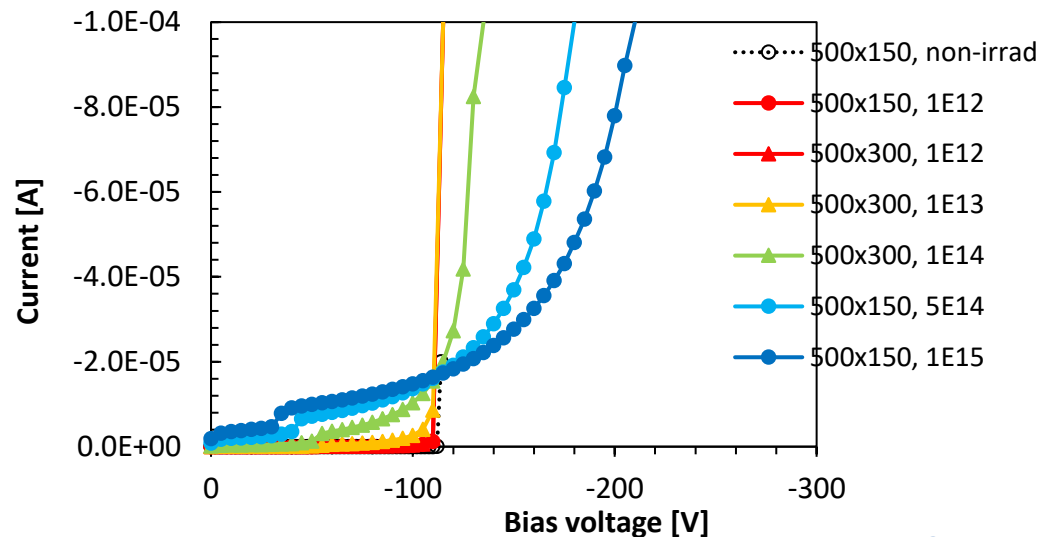
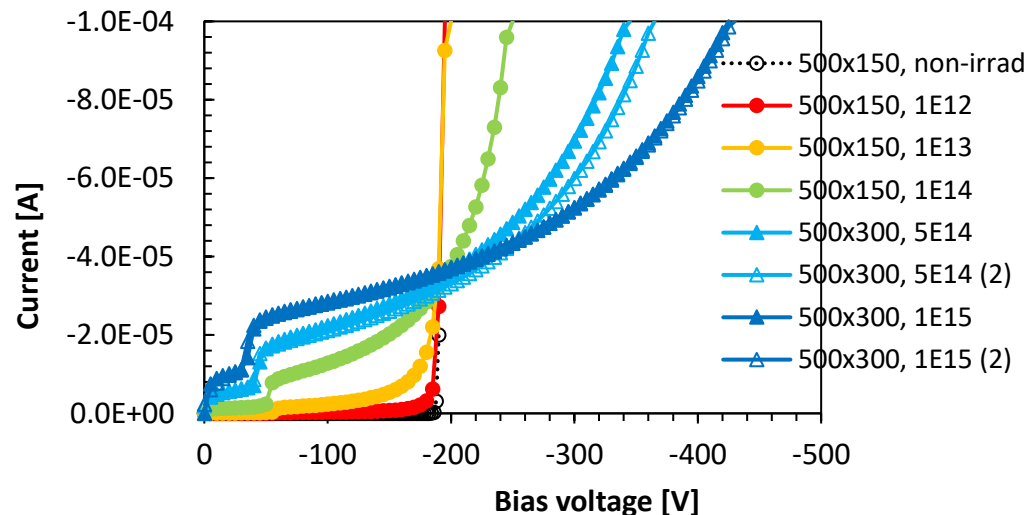
Fluence	0.5 cm	1 cm	2 cm
1.00E+14	52	52	
5.00E+14	44		48
1.00E+15		38	42

Fluence	0.5 cm	1 cm	2 cm
1.00E+12	54	54	
1.00E+13	42		54
1.00E+14		52	53



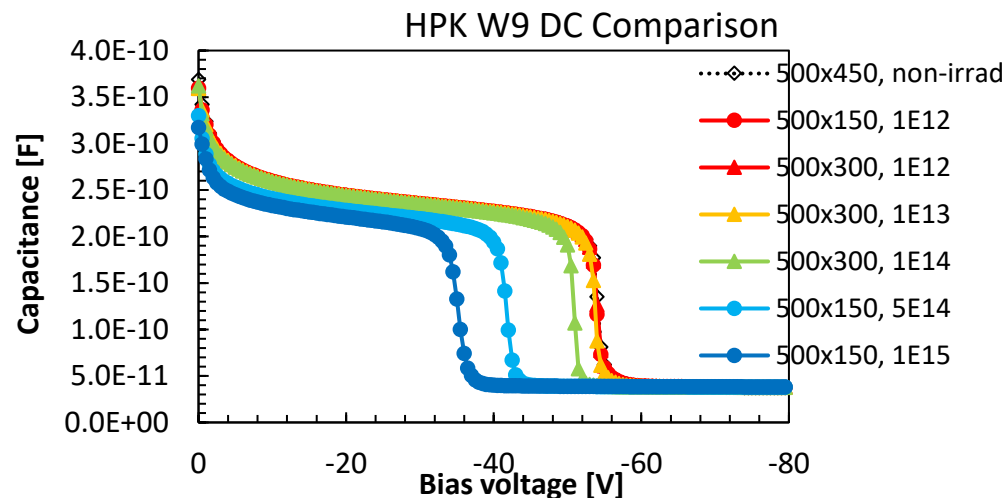
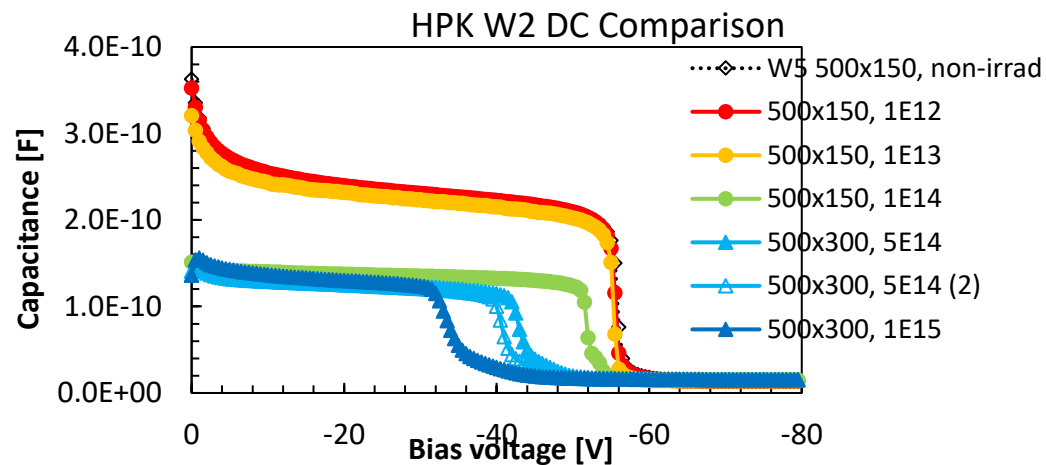
Irradiated AC-LGAD pixels

- Up to $1e13 \text{ cm}^{-2}$, no significant change in sensor properties
- Shift in gain layer depletion voltage is recognizable even in IV measurement
- Leakage current scales with bulk volume: 50 μm thick sensor has higher leakage currents and more prominent 'step' at gain layer depletion
- Breakdown voltage increases with fluence



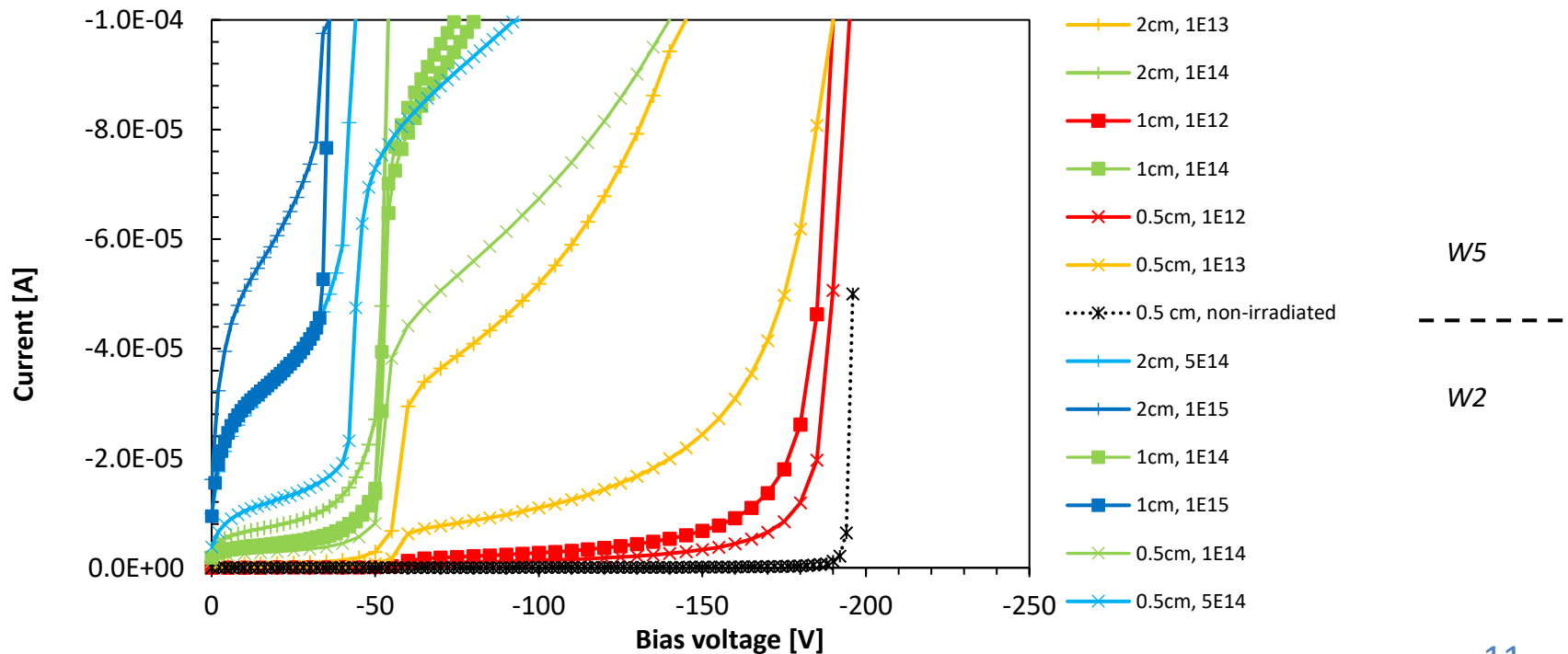
Irradiated AC-LGAD pixels

- Up to $1e13 \text{ cm}^{-2}$, no significant change in gain layer depletion voltage = gain layer active doping concentration
- Shift in gain layer depletion voltage with fluence is very clear
- Behavior across wafers is consistent
 - Note higher full depletion capacitance for thinner sensor
 - More trapping / higher drift time in thicker bulk: affects capacitance before depletion



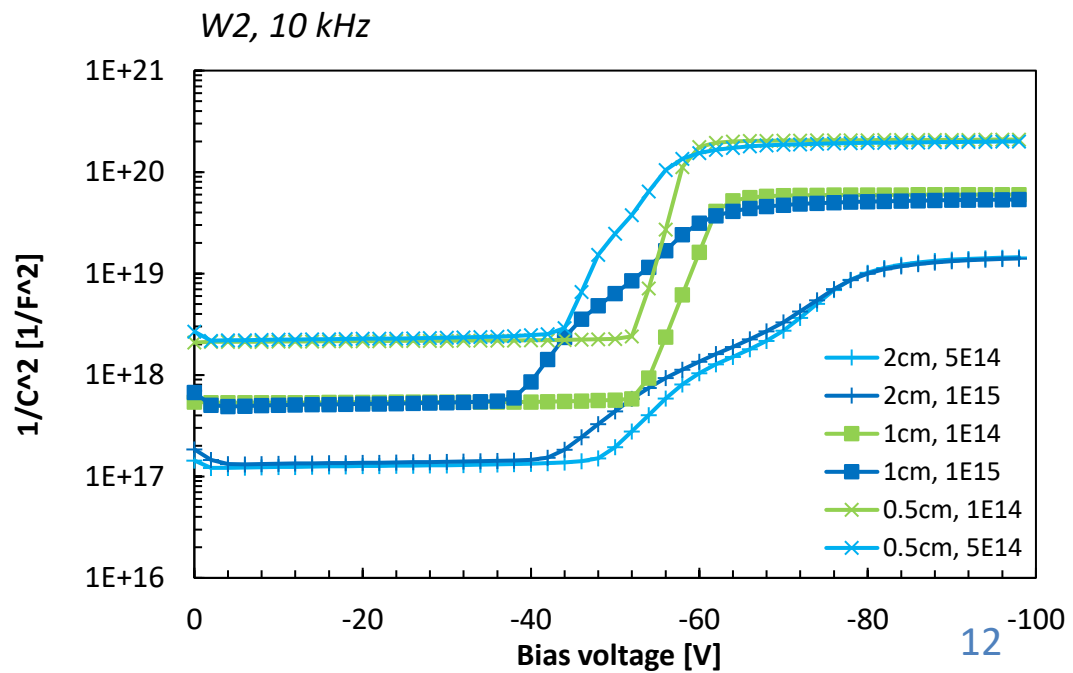
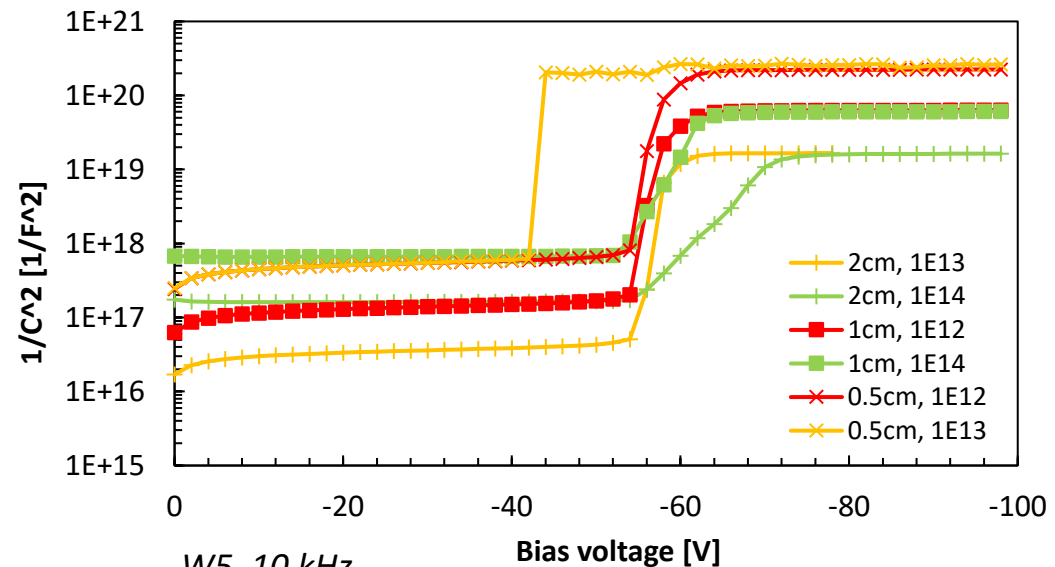
Irradiated AC-LGAD strips

- Strip sensors have larger area, also scales up with strip lengths: changes in leakage current more prominent, already at low fluences after $1e12$
- Shift in gain layer depletion voltage is recognizable even in IV measurement
- (Soft) breakdown voltage may increase with fluence – is overshadowed by too high leakage currents



Irradiated AC-LGAD strips

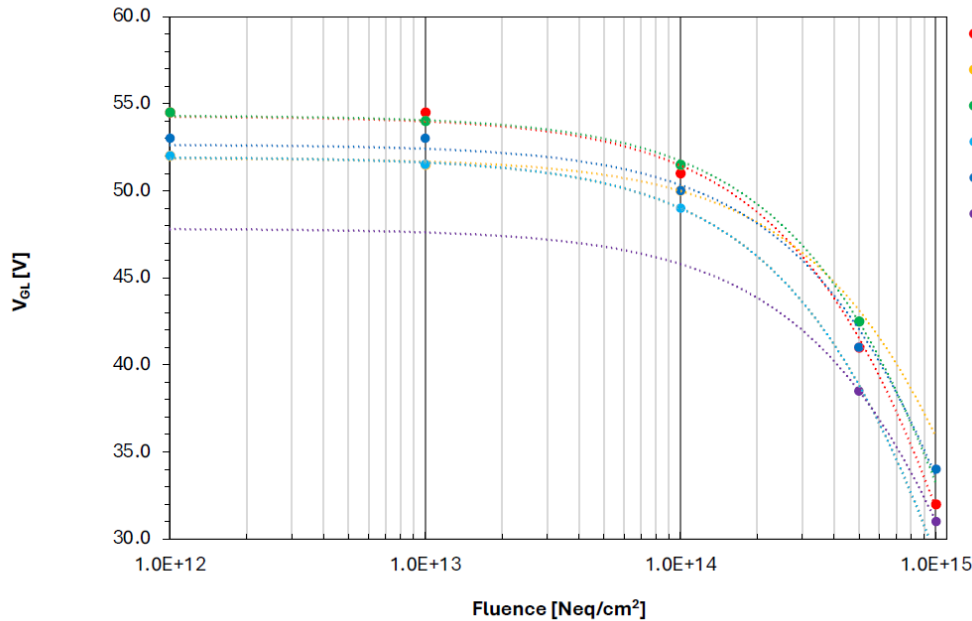
- Up to $1e13 \text{ cm}^{-2}$, no significant change in gain layer depletion voltage = gain layer active doping concentration
- Shift in gain layer depletion voltage with fluence is very clear
- Capacitance scales with surface area / strip length
- Larger sensor: more bulk effects visible after gain layer depletion



Irradiated AC-LGAD pixels

	V(GL) W2	W4	W5	W8	W9	W11
Thickness	50 μm	50 μm	50 μm	50 μm	20 μm	20 μm
Capacitance	240	240	600	600	600	600
N+ resistivity	2	0.5	2	0.5	2	0.5
1.00E+12	54.5	52	54.5	52	53	
1.00E+13	54.5	51.5	54	51.5	53	
1.00E+14	51	50	51.5	49	50	
5.00E+14	41		42.5		41	38.5
1.00E+15	32				34	31

V_{GL} vs Fluence for Pixels



- W2 $y = 54.27e^{-5.38E-16x}$
- W4 $y = 51.86e^{-3.69E-16x}$
- W5 $y = 54.31e^{-4.93E-16x}$
- W8 $y = 51.92e^{-5.81E-16x}$
- W9 $y = 52.64e^{-4.54E-16x}$
- W11 $y = 47.82e^{-4.33E-16x}$

Formula for Fit: $N_D = N_0 e^{-c\Phi}$

c factors:

W2: $5.38 \cdot 10^{-16}$

W4: $3.69 \cdot 10^{-16}$

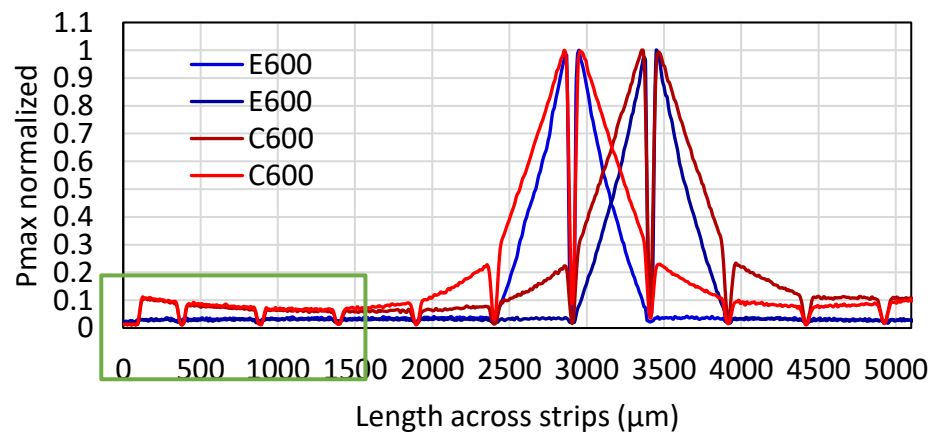
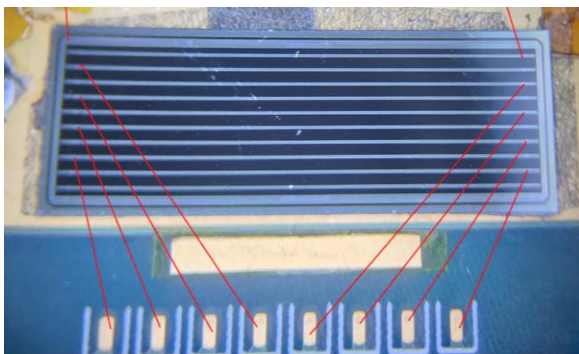
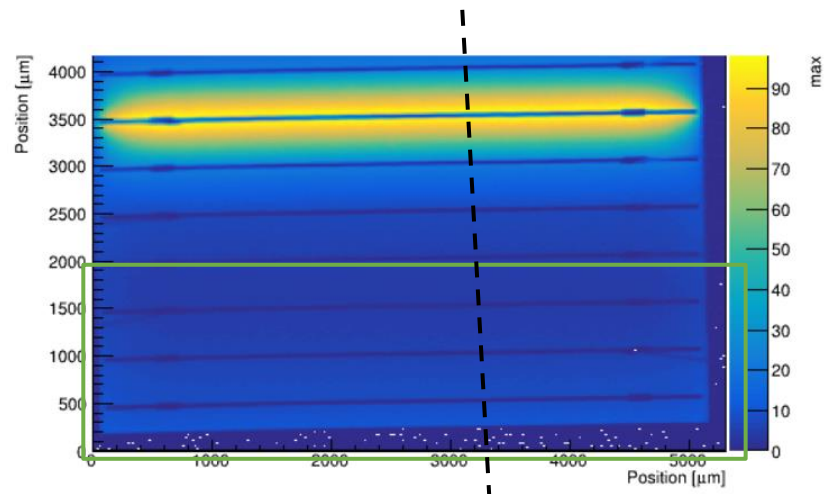
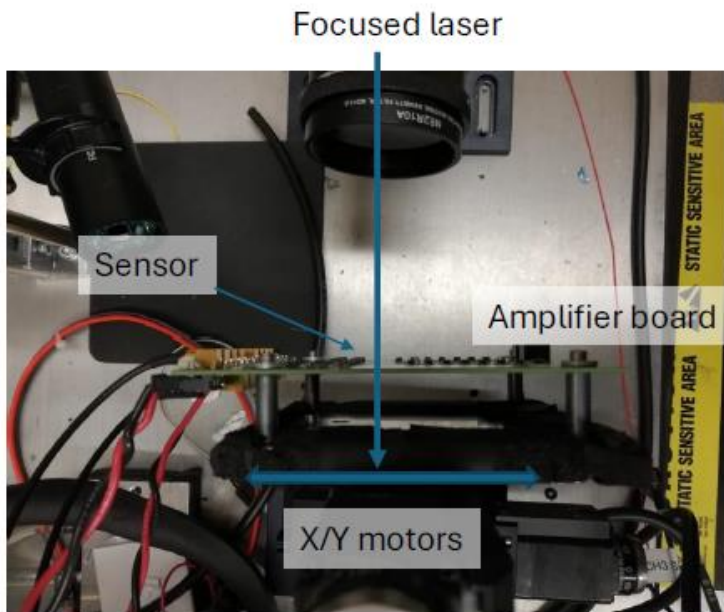
W5: $4.93 \cdot 10^{-16}$

W8: $5.81 \cdot 10^{-16}$

W9: $4.54 \cdot 10^{-16}$

W11: $4.33 \cdot 10^{-16}$

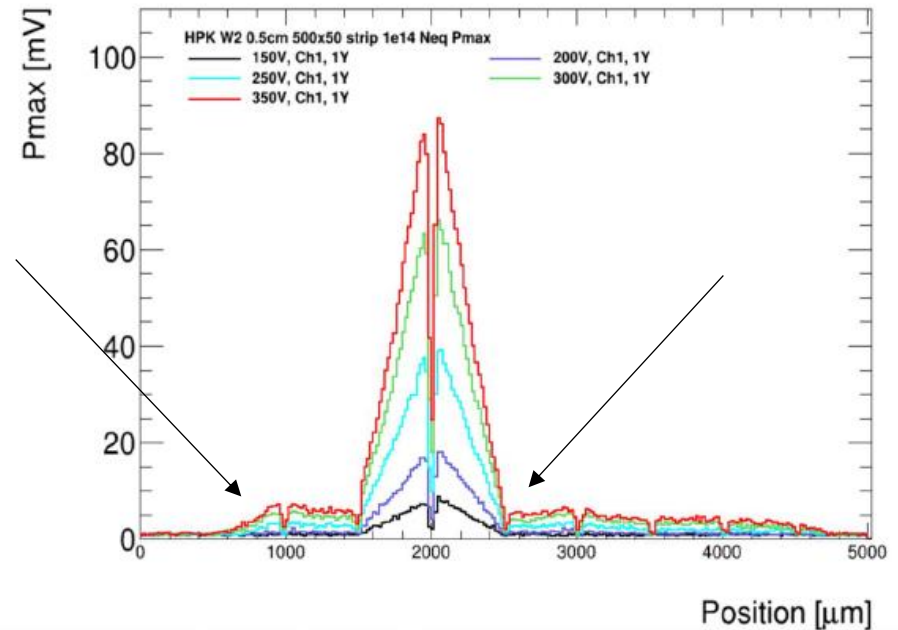
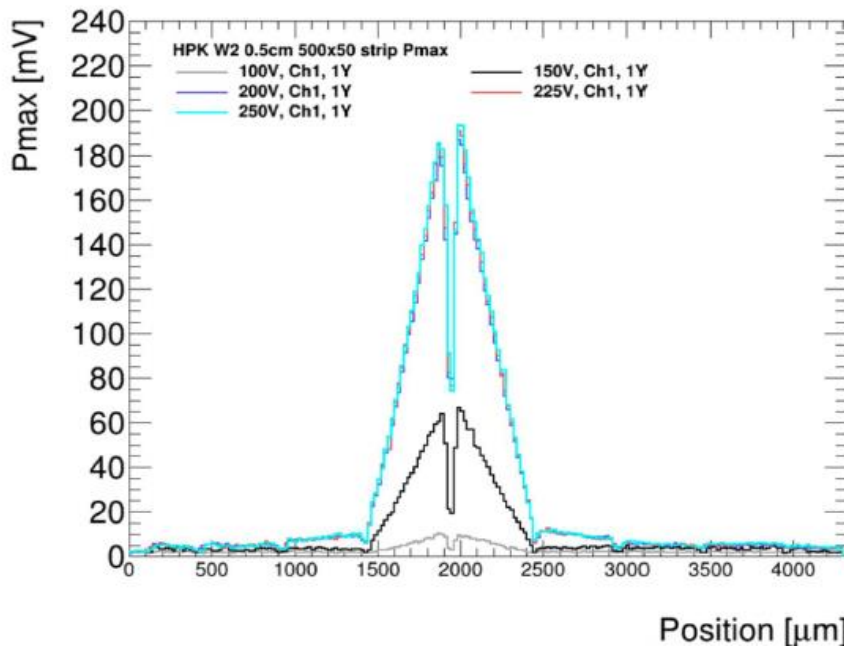
Laser scanning setup





Irradiated AC-LGAD sensors

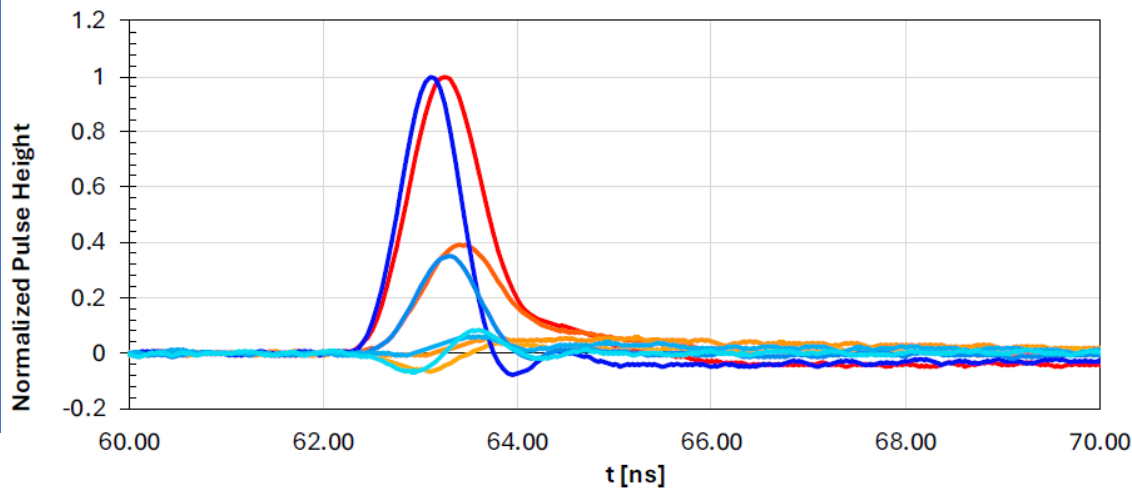
- W2 0.5 cm strip, non-irradiated sensor and irradiated to $1e14$ n/cm²
- Cooling with chiller to ~ 10 C
- Irradiated sensor was biased to higher voltages
- Pmax profile of the main strip is very similar, but increases beyond the first neighboring strip and at longer distances
 - **Indicating higher conductivity of the n+ layer and/or radiation damage to dielectric**



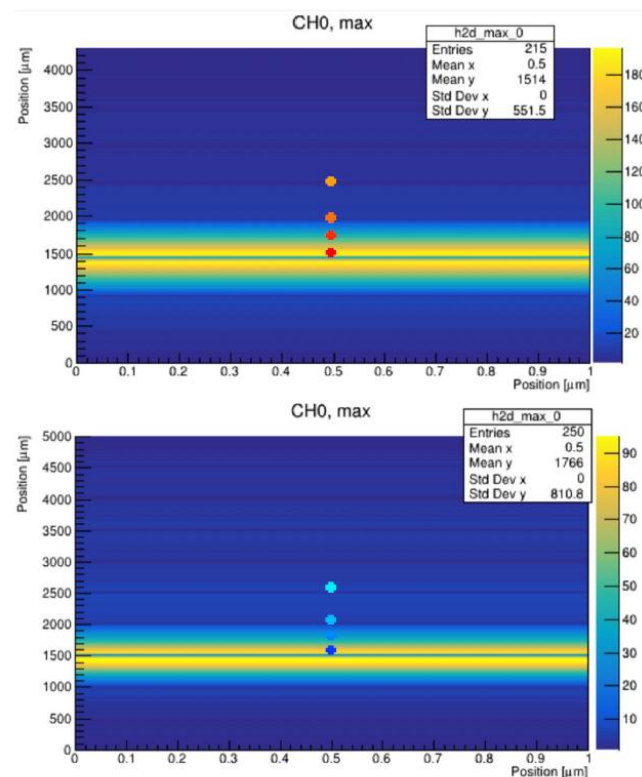
Irradiated AC-LGAD sensors

- Higher leakage current, higher breakdown voltage, **lower gain** in irradiated sensors at $1e14 \text{ n/cm}^2$
- **Faster rise time and shorter pulse in irradiated sensor**
 - More distinct rise and fall as opposed to 'tail' after main pulse

HPK W2 0.5cm strip, 500x50, Normalized Pulses Before/After Irradiation



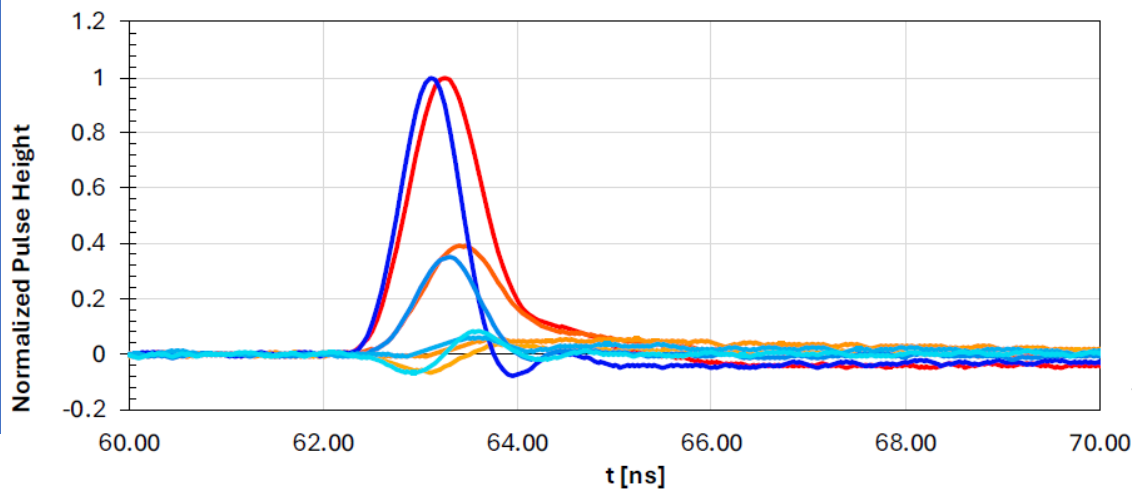
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- Pitch 0.5 (Pre-Irr)
- Pitch 1 (Pre-Irr)
- Pitch 2 (Pre-Irr)
- Pitch 0 (Irr)
- Pitch 0.5 (Irr)
- Pitch 1 (Irr)
- Pitch 2 (Irr)



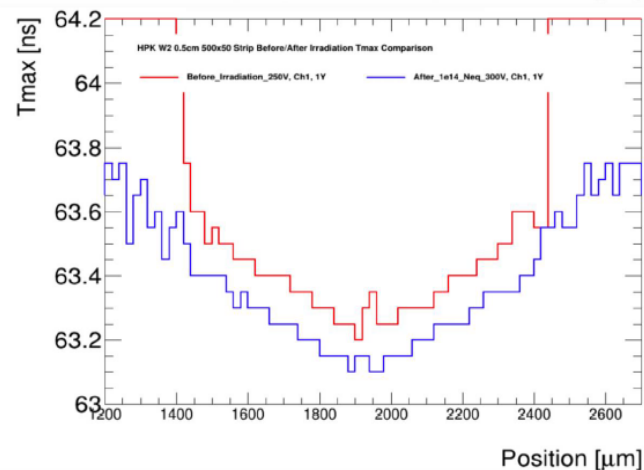
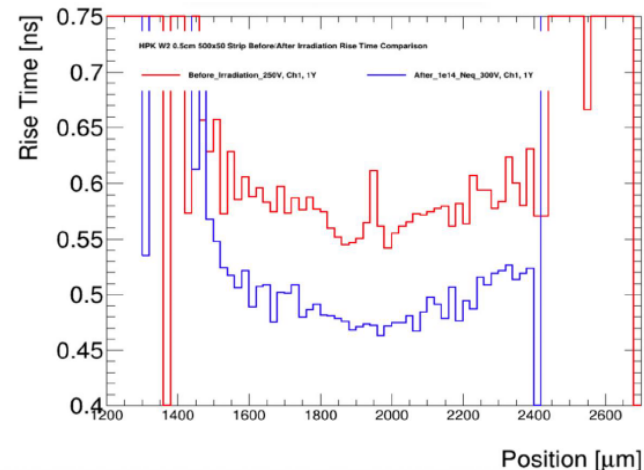
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HPK W2 0.5cm strip, 500x50, Normalized Pulses Before/After Irradiation

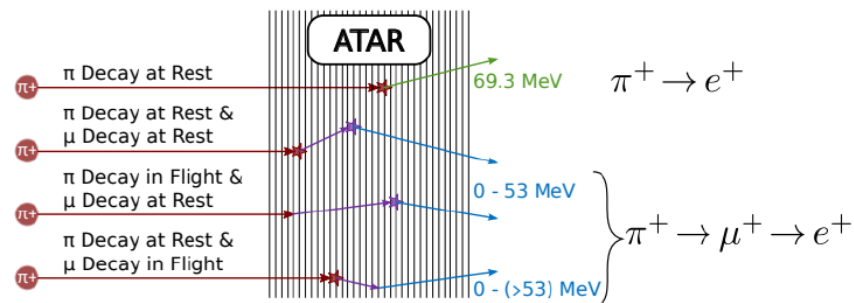
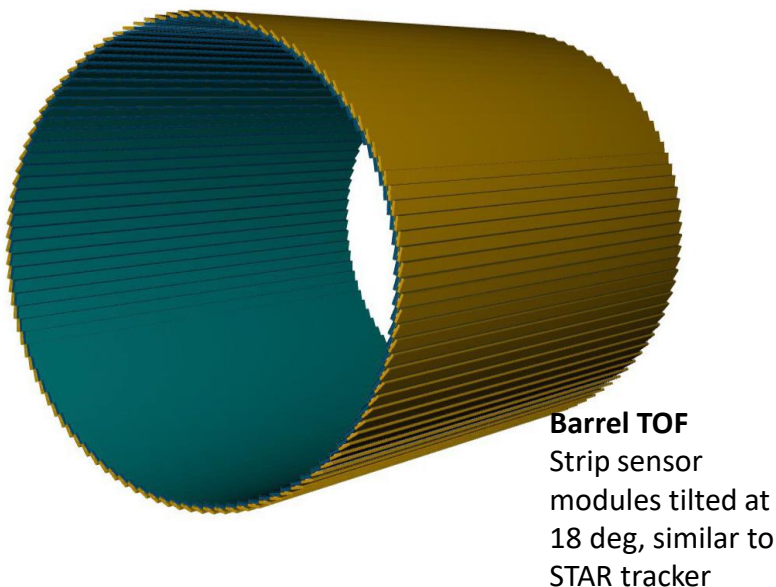


— Pitch 0 (Pre-Irr) — Pitch 0.5 (Pre-Irr) — Pitch 1 (Pre-Irr) — Pitch 2 (Pre-Irr)
— Pitch 0 (Irr) — Pitch 0.5 (Irr) — Pitch 1 (Irr) — Pitch 2 (Irr)



Angular incidence

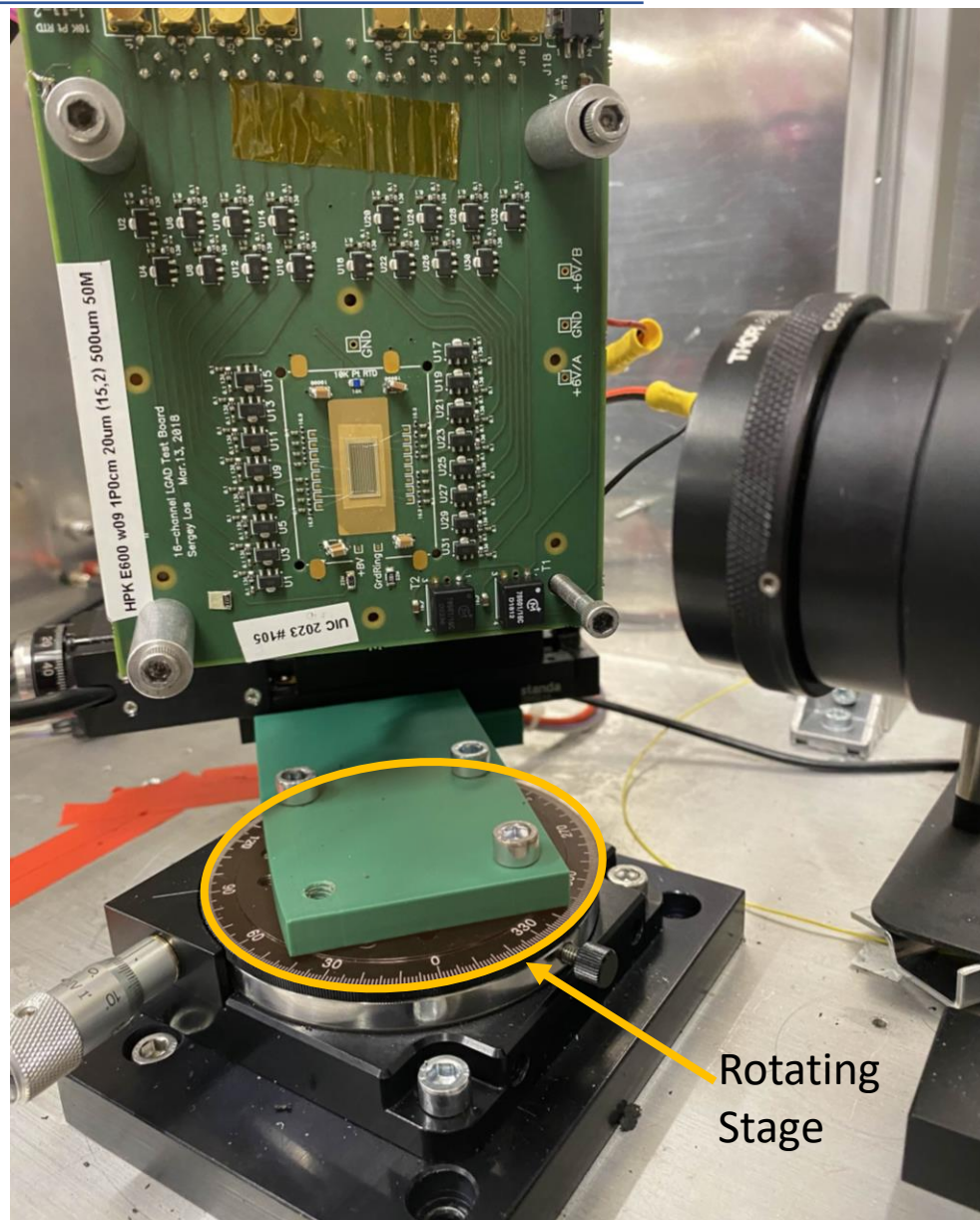
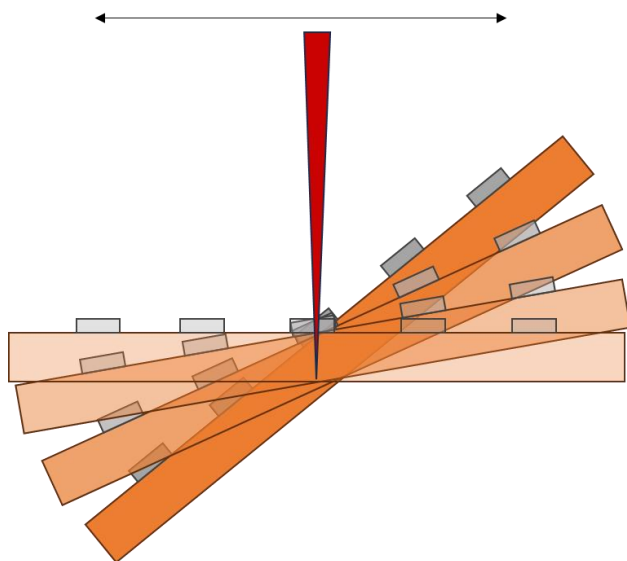
- Laboratory characterization and beam tests so far have been conducted at normal incidence
- Strip modules in ePIC barrel-TOF are layered with a 18-degree tilt angle in the design baseline, forward disk region may also get tracks at high η
- PIONEER ATAR involves several decay scenarios (in-flight, at-rest) and tracks from pions, muons and positrons: decay products can be emitted at large angle respective to strip plane



PIONEER ATAR
Strips orthogonal to beam, but there will be other particle species

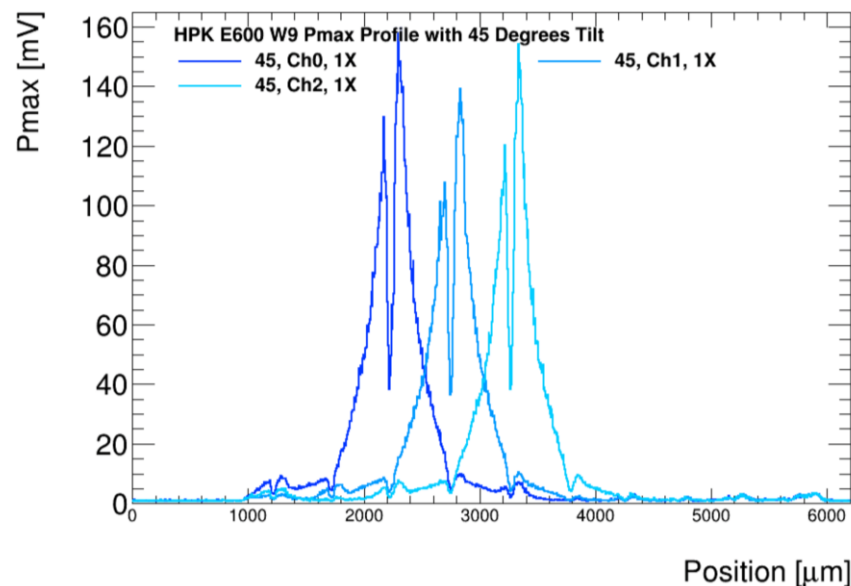
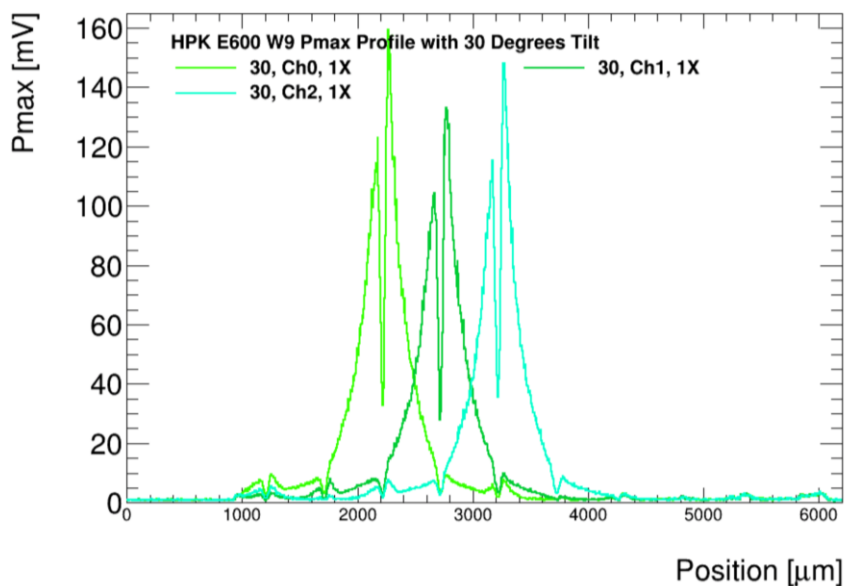
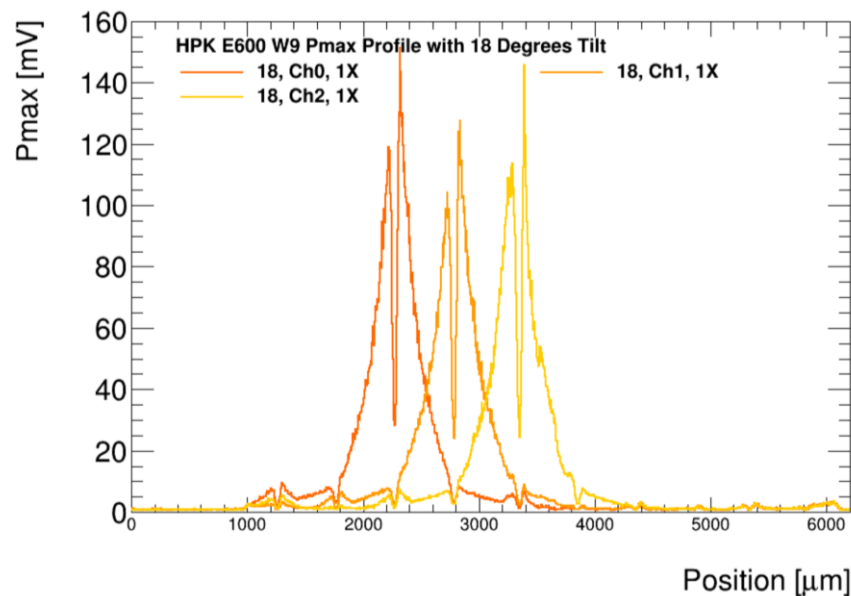
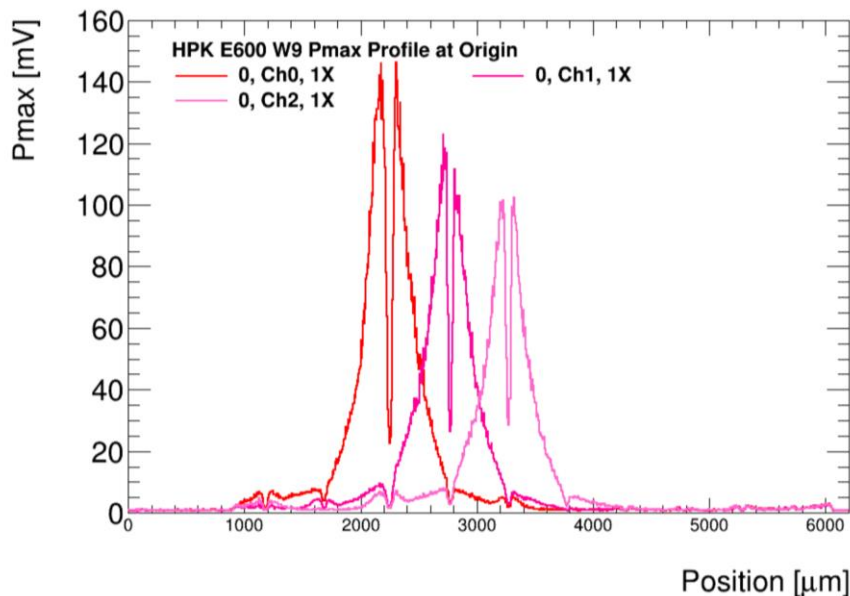
Rotation stage laser setup

- Rotational stage at the base of the x-y scanning system
- 1 cm strip length, 500 μm pitch, 50 μm strip width, W9 (20 μm active thickness)
- Example: setup when taking data at a 45° tilt (technically, at 315°)
- Line scans across the middle of the sensor at: 0°, 18°, 30° and 45°, refocusing at each position



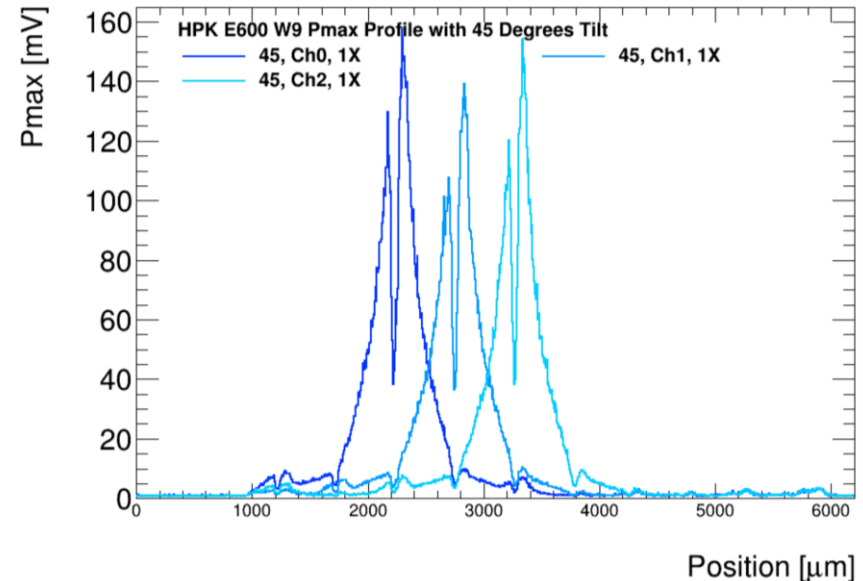
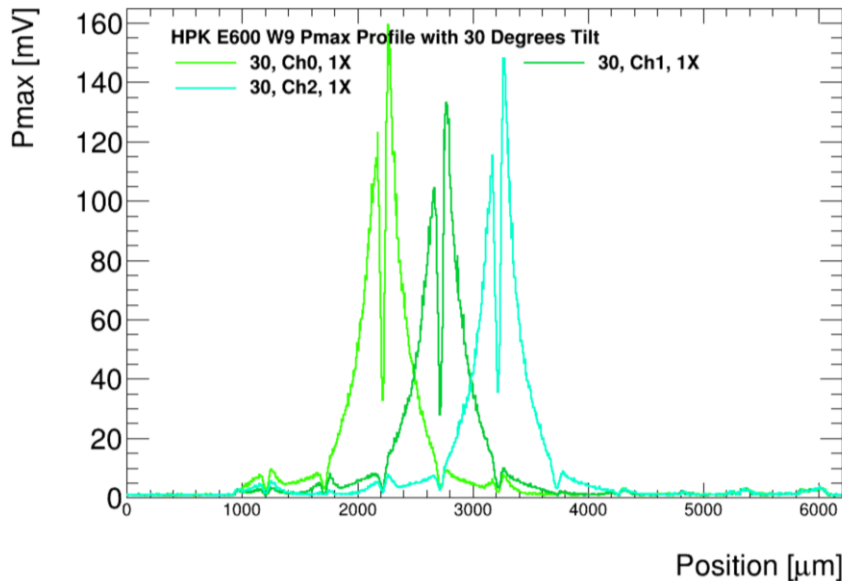
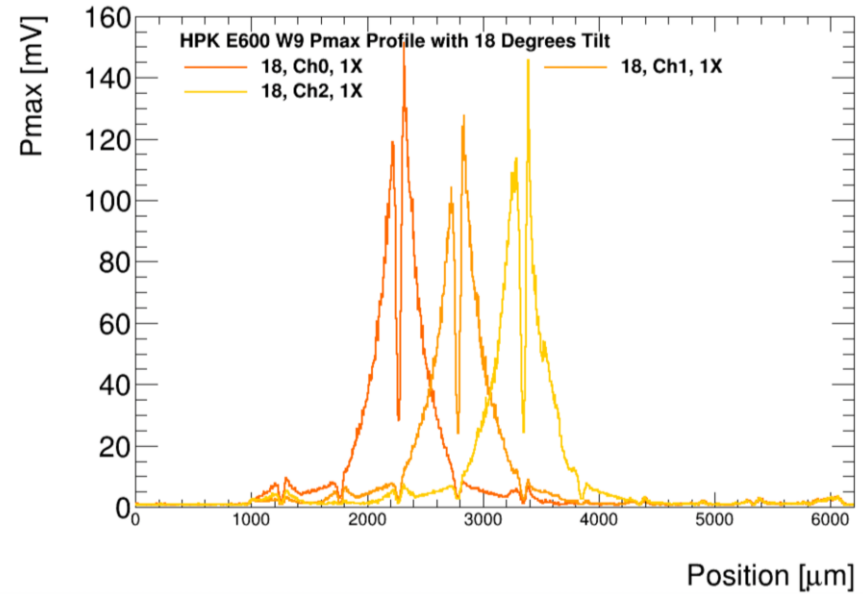


Laser hits at angular incidence



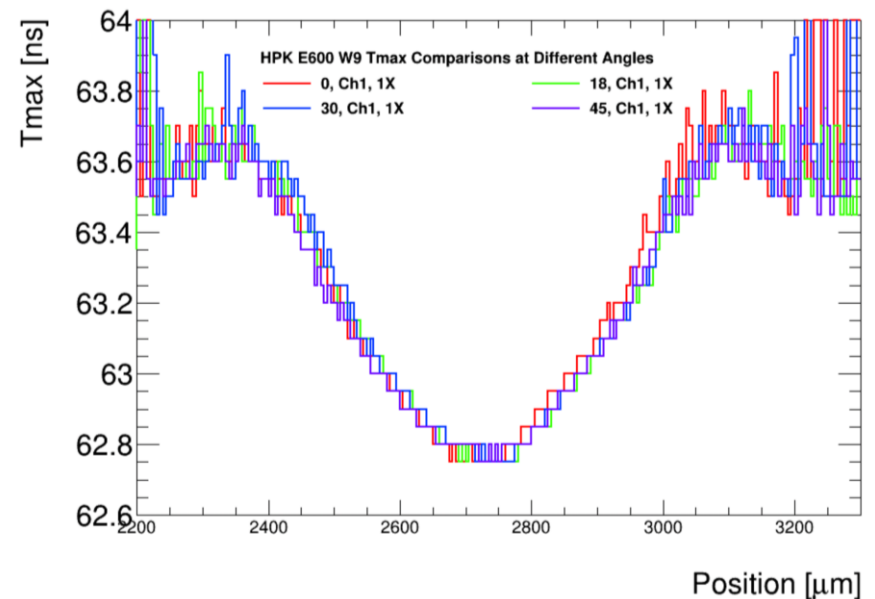
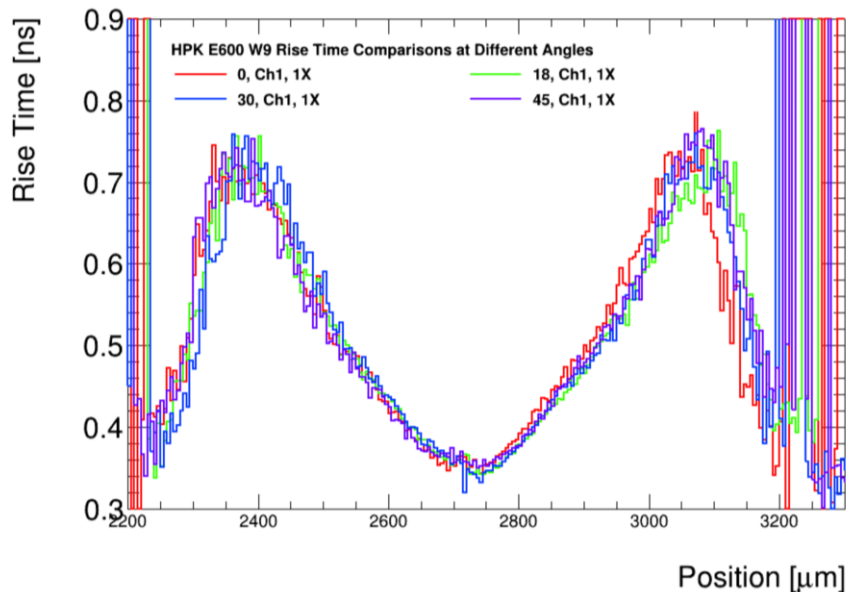
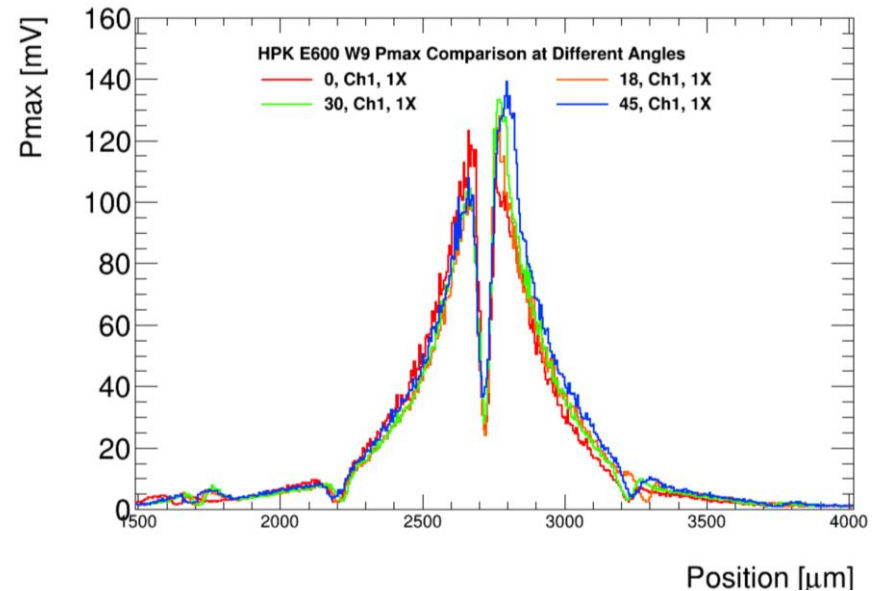
Laser hits at angular incidence

- At larger angles, signal profile in neighboring strips also shows shift with rotational angle
- Laser light is shone under strips – ‘gap’ disappears



Laser hits at angular incidence

- Differences in time-of-arrival and rise time are minimal for the angles measured here





Summary and outlook

- AC-LGADs are radiation hard in terms of leakage current and gain layer to the fluences that are expected at ePIC, even with some margin: no impact of $1e13$ n/cm² in baseline design strip and pad sensors; even $1e14$ n/cm² has moderate effect
 - In large-volume Si, bulk trapping and leakage current generation effects can be pronounced even at relatively low fluences
 - Interesting effects in the charge sharing profile are observed in AC-LGAD strips at higher fluences: to be investigated further
 - **AC and interstrip capacitance and resistance measurements**
 - **Verification with a larger statistical sample**
 - Irradiation with charged particles, electrons and gamma should be conducted
- Angular incidence at the angles studied is visible in charge sharing profile, but no apparent impact on rise time and time-of-arrival
- Irradiated and tilted sensors should be tested in a MIP(-like) test beam

Thank you!



Backup

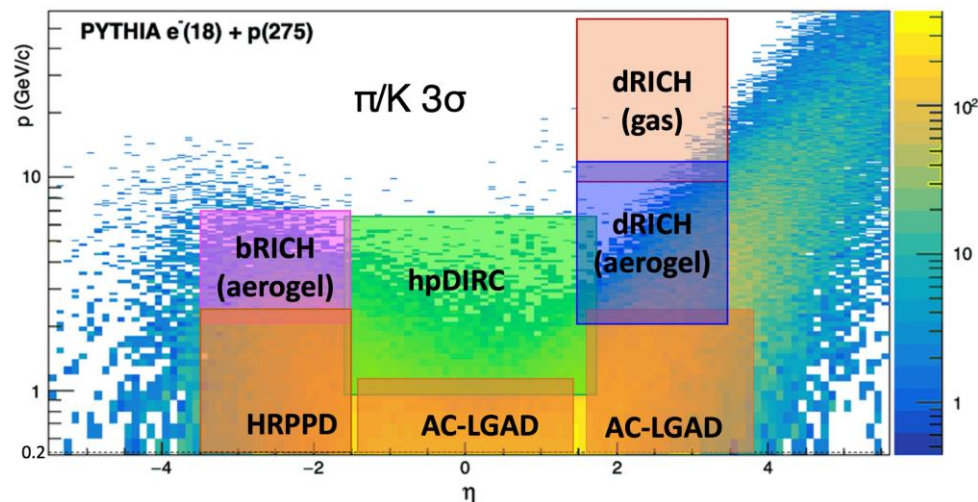
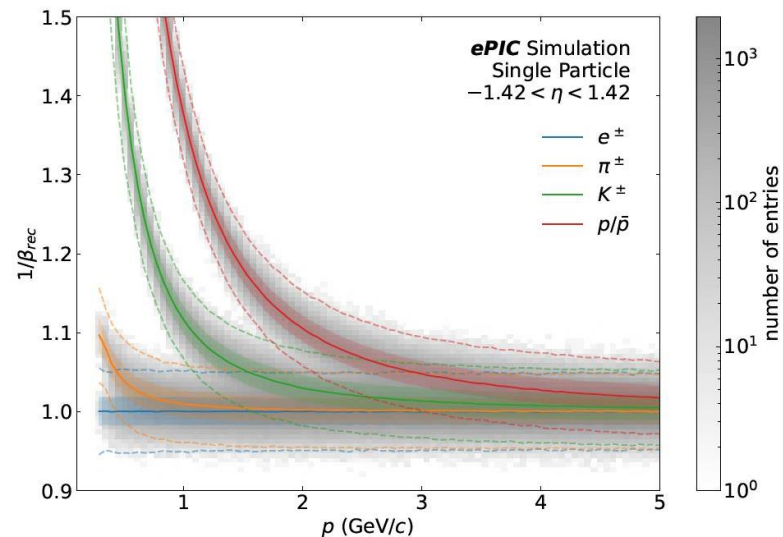


Irradiation campaign for AC-LGADs

- Radiation levels are much lower at the EIC (and future Higgs Factory / FCC-ee) than at e.g. the HL-LHC, but the impact of radiation damage has not been extensively studied for AC-LGADs specifically
- Subset of HPK (and BNL) sensors was selected for irradiation with 800 MeV protons at Los Alamos LANSCE
 - Focus on E type
 - Focus on 600 pF/mm² dielectric capacitance
 - Focus on 1cm strip length, 100 μm strip width; 150 μm pad size
- Total fluences between 1e13 and 2e14 p/cm² – higher than envisioned at the EIC over the full time of life
- Including attempts at **graded irradiation of strip sensors to study the effects of non-uniform degradation of the gain layer and n-layer** within a long sensor
- Sensors were ultimately transferred to Fermilab Irradiation Test Area – to be delivered soon

Particle-ID in ePIC

- Several detectors for particle ID in inner or outer barrel layers, hadronic endcap, electron endcap
 - Momentum and rapidity range cannot be covered by a single technology
 - Leveraging variants of Cherenkov detectors
 - AC-LGADs replaced by picosecond photodetectors in electron (backward) endcap
 - Excellent performance in distinction of charged particle species at low momenta < 3 GeV
- AC-LGAD barrel and forward-endcap Time-of-Flight PID
 - **Combination of precise temporal and spatial resolution: 25 ps and 30 μm / hit**
 - Low material budget
- Current sensor design baseline:
 - Barrel: **strips, 500 μm pitch and 1 cm length**
 - Hadronic endcap (and Roman Pots): **pads, 500 x 500 μm**



Particle ID systems in ePIC

PIONEER Experiment

- Precision experiment at PSI to determine the branching ratio of charged pion decays: involves several decay scenarios (in-flight, at-rest) and tracks from pions, muons and positrons
- Design baseline for the Active TARget: 2x2 cm² area with 48 planes of 120 μm thick AC-LGAD strips, pitch ca. 200 μm
 - Large energy deposition by stopping particles: need sufficient charge sharing to provide good spatial resolution, but not enough to occupy large areas of the sensor from one hit

